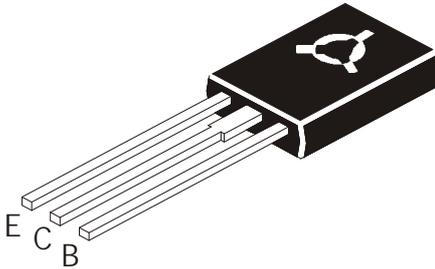


NPN EPITAXIAL SILICON POWER TRANSISTORS

**BD135 BD137
BD139**

**TO126
Plastic Package**



Designed for use as Audio Amplifier and Drivers Utilizing

Complementary BD136, BD138, BD140

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	BD135	BD137	BD139	UNIT
Collector -Emitter Voltage	V_{CEO}	45	60	80	V
Collector -Emitter Voltage ($R_{BE}=1kW$)	V_{CER}	45	60	100	V
Collector -Base Voltage	V_{CBO}	45	60	100	V
Emitter Base Voltage	V_{EBO}	5.0			V
Collector Current	I_C	1.5			A
Collector Peak Current	I_{CM}	2.0			A
Base Current	I_B	0.5			A
Power Dissipation @ $T_a=25^{\circ}C$	P_D	1.25			W
Derate above $25^{\circ}C$		10			mW/ $^{\circ}C$
Power Dissipation @ $T_c=25^{\circ}C$	P_D	12.5			W
Derate above $25^{\circ}C$		100			mW/ $^{\circ}C$
Power Dissipation @ $T_c=70^{\circ}C$	P_D	8.0			W
Operating And Storage Junction Temperature Range	T_j, T_{stg}	- 55 to +150			$^{\circ}C$

THERMAL CHARACTERISTICS

Junction to Ambient in free air	$R_{th(j-a)}$	100	$^{\circ}C/W$
Junction to Case	$R_{th(j-c)}$	10	$^{\circ}C/W$

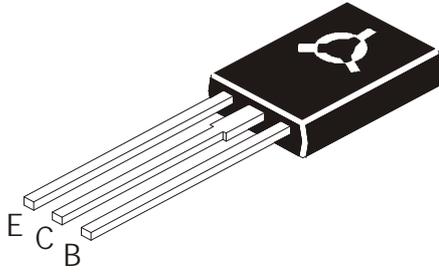
ELECTRICAL CHARACTERISTICS ($T_c=25^{\circ}C$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Collector Emitter Sustaining Voltage	* $V_{CEO(sus)}$	$I_C=30mA, I_B=0$			
			BD135	45	V
			BD137	60	V
			BD139	80	V
Collector Cut off Current	I_{CBO}	$V_{CB}=30V, I_E=0$		0.1	μA
		$V_{CB}=30V, I_E=0, T_c=125^{\circ}C$		10	μA
Emitter Cut off Current	I_{EBO}	$V_{EB}=5V, I_C=0$		10	μA
DC Current Gain	* h_{FE}	$I_C=0.005A, V_{CE}=2V$	25		
		$I_C=0.15A, V_{CE}=2V$	40	250	
		$I_C=0.5A, V_{CE}=2V$	25		

*Pulse test:- Pulse width=300ms, duty cycle=2%

NPN EPITAXIAL SILICON POWER TRANSISTORS

BD135 BD137
BD139



TO126
Plastic Package

ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$ unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
DC Current Gain	* h_{FE} Group	$I_C=0.15\text{A}$, $V_{CE}=2\text{V}$			
		- 6	40	100	
		- 10	63	160	
		- 16	100	250	
		- 25	160	400	
Collector Emitter Saturation Voltage	* $V_{CE(sat)}$	$I_C=0.5\text{A}$, $I_B=0.05\text{A}$		0.5	V
Base Emitter On Voltage	* $V_{BE(on)}$	* $I_C=0.5\text{A}$, $V_{CE}=2\text{V}$		1.0	V

*Pulse test:- Pulse width=300~~ms~~ μs , duty cycle=2%

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

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Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.
Telephone + 91-11-2579 6150, 4141 1112 Fax + 91-11-2579 5290, 4141 1119
email@cdil.com www.cdilsemi.com

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